#### 4 Data Lane 2:1 MIPI Switch

#### **Features**

10-Channel 2:1 Switch

Signal Types: MIPI, D-PHY & C-PHY

Supply Voltage Range(Vcc): 1.65V to 5.0V

Input Signals: 0V to 1.3V

Ron: 7Ω Typical

ΔR<sub>ON</sub>: 0.1Ω Typical

I<sub>CC</sub>: 25µA Typical

-3dB Bandwidth: 4.5 GHz Typical

Low Crosstalk: -30 dB Typical

Low Off Isolation: -24 dB Typical

Con: 1.4 pF Typical

# General Description

The AW35646 is a four-data-lane MIPI D-PHY switch. The AW35646 can also be configured as three-data-lane MIPI C-PHY switch.

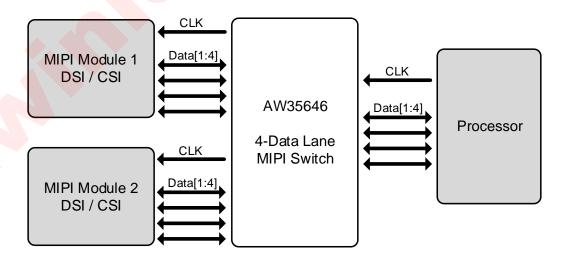
This 10 channel single-pole double-throw switch is optimized for high speed MIPI applications. The AW35646 is designed to facilitate multiple MIPI compliant devices to connect to a CSI or DSI module.

The AW35646 is available in a WLCSP 2.43mmX2.43mmX0.488mm-36B package.

## **Applications**

- Smartphones
- Tablets
- Laptops
- Displays

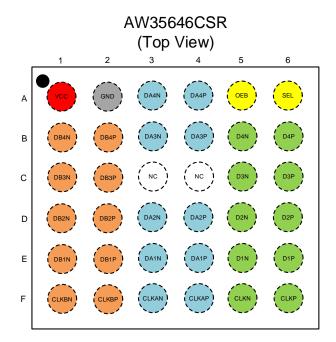
## **Typical Application Circuit**

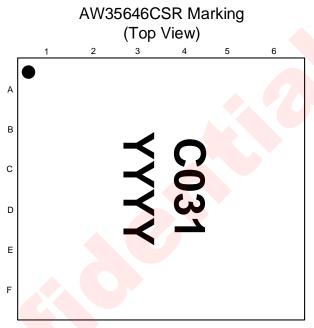


**Typical Application Circuit of AW35646** 

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## **Pin Configuration And Top Mark**





C031 - AW35646CSR YYYY - Production Tracing Code

Pin Configuration and Top Mark

#### **Pin Definition**

PIN	NAME	DESCRIPTION				
A1	VCC	Power supply input				
A2	GND	Ground				
A3	DA4N	A side data port 4, differential -				
A4	DA4P	A side data port 4, differential +				
A5	OEB	Output enable, active low				
A6	SEL	Channel select				
B1	DB4N	B side data port 4, differential -				
B2	DB4P	B side data port 4, differential +				
В3	DA3N	A side data port 3, differential -				
B4	DA3P	A side data port 3, differential +				
B5	D4N	Common data port 4, differential -				
B6	D4P	Common data port 4, differential +				

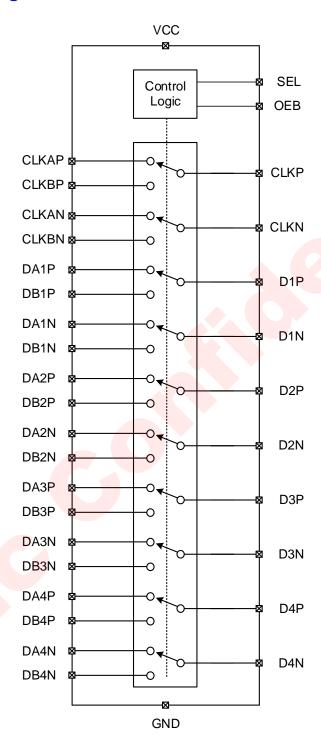
# Pin Definition (Continued)

PIN	NAME	DESCRIPTION
C1	DB3N	B side data port 3, differential -
C2	DB3P	B side data port 3, differential +
C3	NC	No connect
C4	NC	No connect
C5	D3N	Common data port 3, differential -
C6	D3P	Common data port 3, differential +
D1	DB2N	B side data port 2, differential -
D2	DB2P	B side data port 2, differential +
D3	DA2N	A side data port 2, differential -
D4	DA2P	A side data port 2, differential +
D5	D2N	Common data port 2, differential -
D6	D2P	Common data port 2, differential +
E1	DB1N	B side data port 1, differential -
E2	DB1P	B side data port 1, differential +
E3	DA1N	A side data port 1, differential -
E4	DA1P	A side data port 1, differential +
E5	D1N	Common data port 1, differential -
E6	D1P	Common data port 1, differential +
F1	CLKBN	B side clock port, differential -
F2	CLKBP	B side clock port, differential +
F3	CLKAN	A side clock port, differential -
F4	CLKAP	A side clock port, differential +
F5	CLKN	Common clock port, differential -
F6	CLKP	Common clock port, differential +

## **Pin Functions**

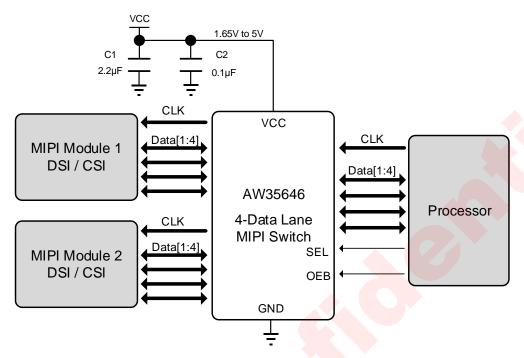
OEB	SEL	Function
Н	X	Clock and Data ports High Impedance
L	L	CLKP/N=CLKAP/N, DnP/N=DAnP/N
L	Н	CLKP/N=CLKBP/N, DnP/N=DBnP/N

## **Functional Block Diagram**

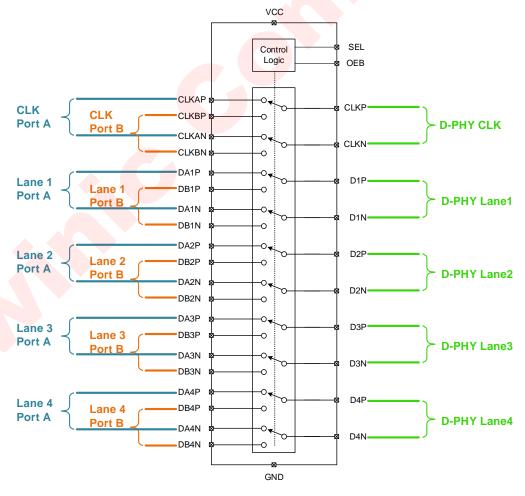


**Functional Block Diagram** 

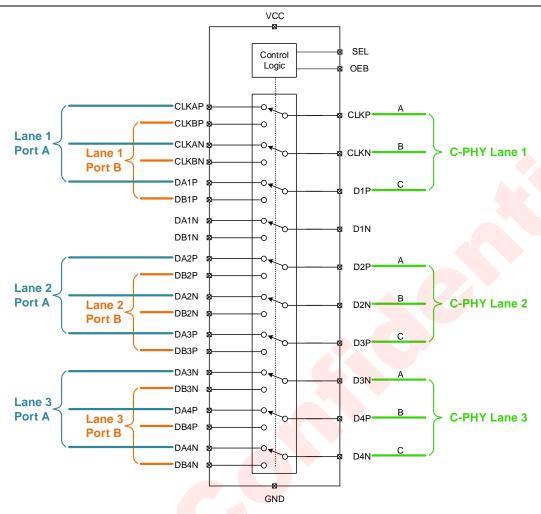
## **Typical Application Circuits**



Typical Application Circuit of AW35646



Recommended D-PHY Configuration of AW35646



#### Recommended C-PHY Configuration of AW35646

The control inputs OEB,SEL must be held HIGH or LOW, and cannot be left floating

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## **Ordering Information**

Part Number	Temperature	Package	Marking	Moisture Sensitivity Level	Environmental Information	Delivery Form
AW35646CSR	-40°C∼85°C	WLCSP 2.43mmX2.43mm X0.488mm-36B	C031	MSL1	ROHS+HF	3000 units/ Tape and Reel

# **Absolute Maximum Ratings**(NOTE1)

PARAMETER	RANGE			
Supply voltage range	-0.3V to 6V			
Input/Output DC switch vol	tage V <sub>I/O</sub> (NOTE2)	-0.3V to 6V		
Input voltage range	SEL, OEB	-0.3V to 6V		
Junction-to-ambient therma	I resistance θ <sub>JA</sub>	61°C/W		
Maximum operating junction to	empe <mark>rature T<sub>JMAX</sub></mark>	150°C		
Operating free-air tempe	Operating free-air temperature range			
Storage temperature	-65°C to 150°C			
Lead temperature (solderin	260°C			
Human Body M <mark>odel (All pins, pe</mark> r ANS	±2kV			
Charged Device Model (All pins,	±1kV			
Machine Model (All pins, per	±200V			
Test condition: JED	DEC78	±200mA		

NOTE1: Conditions out of those ranges listed in "absolute maximum ratings" may cause permanent damages to the device. In spite of the limits above, functional operation conditions of the device should within the ranges listed in "recommended operating conditions". Exposure to absolute-maximum-rated conditions for prolonged periods may affect device reliability.

NOTE2: V<sub>I/O</sub> refers to analog data/clock switch ports

## **Electrical Characteristics**

 $T_A = -40$ °C to 85°C unless otherwise noted. Typical values are guaranteed for  $V_{CC} = 3.3$ V  $T_A = 25$ °C.

F	PARAMETER	TEST CONDITION	MIN	TYP	MAX	UNIT
Vcc	Supply voltage		1.65	3.3	5.0	V
Icc	Active supply current	OEB=0V, SEL=0V or Vcc		25	45	μΑ
I <sub>CC_PD</sub>	Standby supply current	OEB=V <sub>CC</sub> , SEL=0V or V <sub>CC</sub>			1	μA
I <sub>CC_PD_1.5</sub>	Standby supply current	Vcc=5V OEB=1.5V, SEL=0V or Vcc		1		μА
DC Characte	eristics					
Ron Hs	On-state resistance for	V <sub>I/O</sub> =0.2V, I <sub>ON</sub> =8mA Vcc=1.65V		7	11	Ω
KON_HS	high speed MIPI mode	V <sub>I/O</sub> =0.2V, I <sub>ON</sub> =8mA V <sub>CC</sub> =1.8V to 5.0V		7	11	Ω
Ron lp	On-state resistance for	V <sub>I/O</sub> =1.2V, I <sub>ON</sub> =8mA V <sub>CC</sub> =1.65V		8	12	Ω
TKON_LP	low power MIPI mode	V <sub>I/O</sub> =1.2V, I <sub>ON</sub> =8mA V <sub>CC</sub> =1.8V to 5.0V		7.5	12	Ω
ΔRon_Hs	On-state resistance match between channels for high speed MIPI mode	V <sub>I/O</sub> =0.2V, I <sub>ON</sub> =8mA		0.1		Ω
$\Delta R_{ON\_LP}$	On-state resistance match between channels for low power MIPI mode	V <sub>I/O</sub> =1.2V, I <sub>ON</sub> =8mA		0.1		Ω
Ron_flat_hs	ON-state resistance flatness for high speed MIPI mode	V <sub>I/O</sub> =0V to 0.3V, I <sub>ON</sub> =8mA		0.9		Ω
Ron_flat_lp	ON-state resistance flatness for low power MIPI mode	V <sub>I/O</sub> =0V to 1.3V, I <sub>ON</sub> =8mA		0.9		Ω
loff	Switch off leakage current	Vcc=1.65V to 5.0V OEB, SEL=0V or 5.0V Dn,CLKn,DAn,CLKAn,DBn, CLKBn=0V to 1.3V	-0.5		0.5	μΑ
Ion	Switch on leakage current	Vcc=1.65V to 5.0V OEB=0V, SEL=0V or 5.0V Dn,CLKn,DAn,CLKAn,DBn, CLKBn=0V to 1.3V	-0.5		0.5	μА

# **Electrical Characteristics (Continued)**

 $T_A = -40$ °C to 85°C unless otherwise noted. Typical values are guaranteed for  $V_{CC} = 3.3$ V  $T_A = 25$ °C.

	PARAMETER	TEST CONDITION	MIN	TYP	MAX	UNIT
Digital Cha	aracteristics					
ViH	Input logic high (SEL, OEB)	Vcc=1.65V to 5.0V	1.3			V
VıL	Input logic low (SEL, OEB)	Vcc=1.65V to 5.0V			0.5	V
ILEAK_IN	Input leakage (SEL, OEB)	SEL,OEB=0V to 5.0V	-0.5		0.5	μΑ
Cin	Digital Input capacitance (SEL, OEB)	f=1MHz		5		pF
Dynamic C	Characteristics					
Сом	ON capacitance <sup>(NOTE3)</sup>	OEB=0V, Dn,CLKn,DAn,DBn,CLKAn, CLKBn=0V or 0.2V f = 1250 MHz, switch ON		1.4		pF
Coff	OFF capacitance <sup>(NOTE3)</sup>	OEB=Vcc, Dn,CLKn,DAn,DBn,CLKAn, CLKBn=0V or 0.2V f = 1250MHz, switch OFF		1.2		pF
Oiso	Differential off isolation <sup>(NOTE3)</sup>	$R_L = 50\Omega$ , $C_L = 0pF$ $V_{I/O}=200mV+200mV_{PP}$ (differential) f = 1250MHz, switch OFF		-24		dB
Xtalk	Differential Channel to channel crosstalk(NOTE3)	$R_L$ = 50 $\Omega$ , $C_L$ = 0pF $V_{I/O}$ =200mV+200mV <sub>PP</sub> (differential) f = 1250MHz, switch ON		-30		dB
BW	-3dB bandwidth <sup>(NOTE3)</sup>	$R_L = 50\Omega$ , $C_L = 0pF$ $V_{I/O}=200mV+200mV_{PP}$ (differential), switch ON		4.5		GHz
ILOSS	Insertion Loss <sup>(NOTE3)</sup>	$R_L$ = 50 $\Omega$ , $C_L$ = 0pF $V_{I/O}$ =200mV+200mV <sub>PP</sub> (differential) f = 750MHz, switch ON		-0.7		dB

NOTE3: Guaranteed by characterization

# **Electrical Characteristics (Continued)**

 $T_A = -40$ °C to 85°C unless otherwise noted. Typical values are guaranteed for  $V_{CC} = 3.3$ V  $T_A = 25$ °C.

	PARAMETER	TEST CONDITION	MIN	TYP	MAX	UNIT
Dynamic C	haracteristics					
t <sub>INIT</sub>	Initialization time (Vcc to output)	Dn,CLKn=0.6V DAn,DBn,CLKAn,CLKBn: $R_L = 50\Omega$ , $C_L = 0$ pF		1.5	200	μs
t <sub>EN</sub>	Device turn on time (OEB to output)	Dn,CLKn=0.6V DAn,DBn,CLKAn,CLKBn: $R_L = 50\Omega$ , $C_L = 0$ pF		0.5	200	μs
t <sub>DIS</sub>	Device turn off time (OEB to output)	Dn,CLKn=0.6V DAn,DBn,CLKAn,CLKBn: $R_L = 50\Omega$ , $C_L = 0$ pF		150	250	ns
ton	Switch turn on time (SEL to output)	Dn,CLKn=0.6V DAn,DBn,CLKAn,CLKBn: $R_L = 50\Omega$ , $C_L = 0$ pF		800	1600	ns
toff	Switch turn off time (SEL to output)	Dn,CLKn=0.6V DAn,DBn,CLKAn,CLKBn: $R_L = 50\Omega$ , $C_L = 0pF$		150	800	ns
t <sub>ввм</sub>	Break before make time	Dn,CLKn: $R_L = 50\Omega$ , $C_L = 0pF$ DAn,DBn,CLKAn,CLKBn =0.6V		400		ns
t <sub>PD</sub>	Propagation delay <sup>(NOTE4)</sup>	Dn,CLKn=0.6V DAn,DBn,CLKAn,CLKBn: $R_L = 50\Omega$ , $C_L = 0$ pF		67		ps
tskew(intra)	Intrapair skew <sup>(NOTE4)</sup>	Dn,CLKn=0.3V DAn,DBn,CLKAn,CLKBn: $R_L = 50\Omega$ , $C_L = 0pF$		6		ps
tskew(inter)	Interpair skew <sup>(NOTE4)</sup>	Dn,CLKn=0.3V DAn,DBn,CLKAn,CLKBn: $R_L = 50\Omega$ , $C_L = 0pF$		6		ps

NOTE4: Guaranteed by characterization

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## **Detailed Functional Description**

The AW35646 is a four-data-lane MIPI D-PHY switch. This device is an optimized 10-channel (5 differential) single-pole, double-throw switch for use in high speed applications. The AW35646 can also be configured as three-data-lane MIPI C-PHY switch. The AW35646 is designed to facilitate multiple MIPI compliant devices to connect to a single CSI/DSI, C-PHY/D-PHY module.

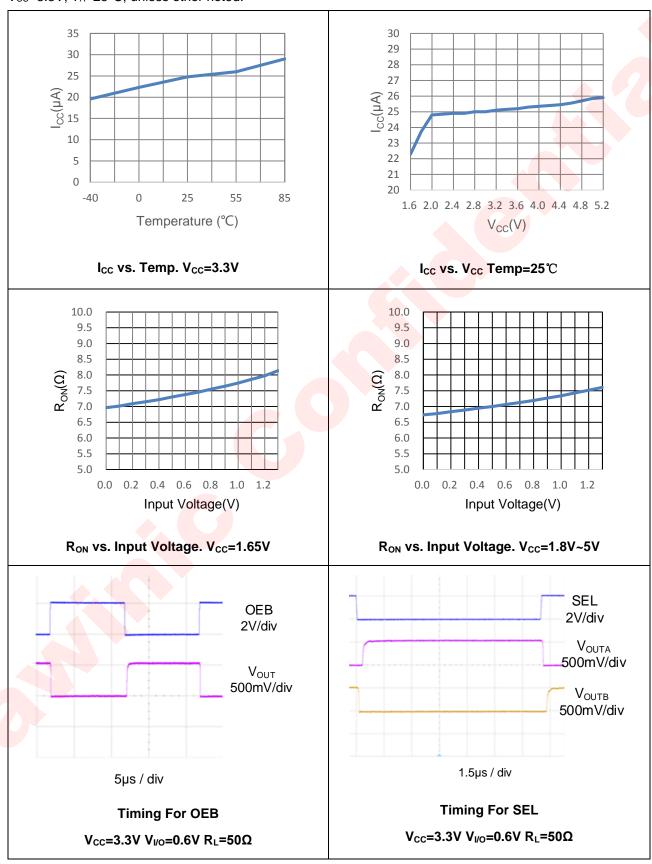
#### High Impedance Mode

When OEB is logic high, the AW35646 is in high impedance mode, all the clock and data ports are in Hi-Z state.

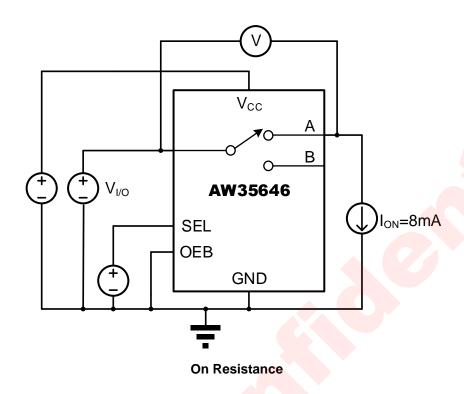
OEB	SEL	Function
Н	Х	Clock and Data ports High Impedance
L	L	CLKP/N=CLKAP/N, DnP/N=DAnP/N
L	Н	CLKP/N=CLKBP/N, DnP/N=DBnP/N

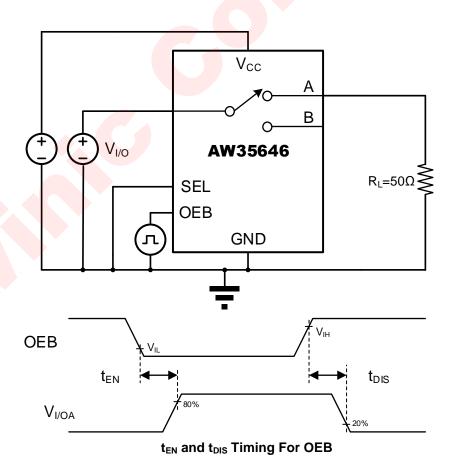
## **Typical characteristics**

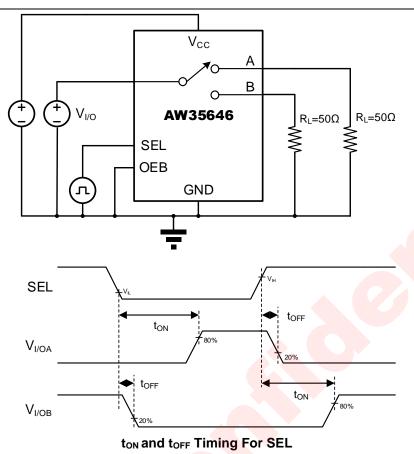
Vcc=3.3V, TA=25°C, unless other noted.

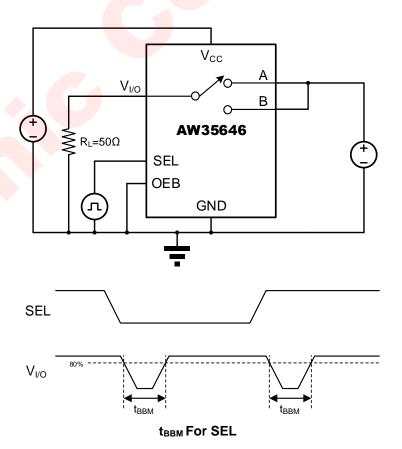


## **Parameter Measurement Information**









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## **PCB Layout Consideration**

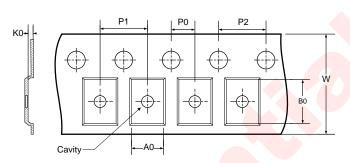
To obtain the optimal performance of AW35646, PCB layout should be considered carefully. Here are some quidelines:

- 1. Place supply bypass capacitors as close to V<sub>CC</sub> and GND pin as possible and avoid placing the bypass capacitors near the high-speed traces.
- 2. The characteristic impedance of the traces must match that of the receiver and transmitter to maintain signal integrity.
- 3. Route the high-speed signals using a minimum amount of vias and corners which reduces signal reflections and impedance changes. When it becomes necessary to make the traces turn 90°, use an arc instead of making a single 90° turn.
- 4. Do not route high-speed traces under or near crystals, oscillators, clock signal generators, switching regulators, mounting holes, magnetic devices or ICs that use or duplicate clock signals.
- 5. Avoid stubs on the high-speed signal lines because they cause signal reflections.
- 6. Route all high-speed signal traces over continuous GND planes, with no interruptions.
- 7. High speed signal traces must be length matched as much as possible to minimize skew between data and clock lines. Width and spacing between differential traces must be equal line width and line spacing

## **Tape And Reel Information**

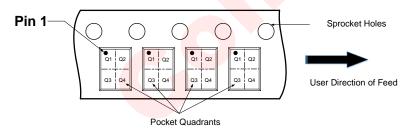
# REEL DIMENSIONS D1 D0

#### TAPE DIMENSIONS



- A0: Dimension designed to accommodate the component width
- B0: Dimension designed to accommodate the component length
- K0: Dimension designed to accommodate the component thickness
- W: Overall width of the carrier tape
- P0: Pitch between successive cavity centers and sprocket hole
- P1: Pitch between successive cavity centers
- P2: Pitch between sprocket hole
- D1: Reel Diameter
  D0: Reel Width

## QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



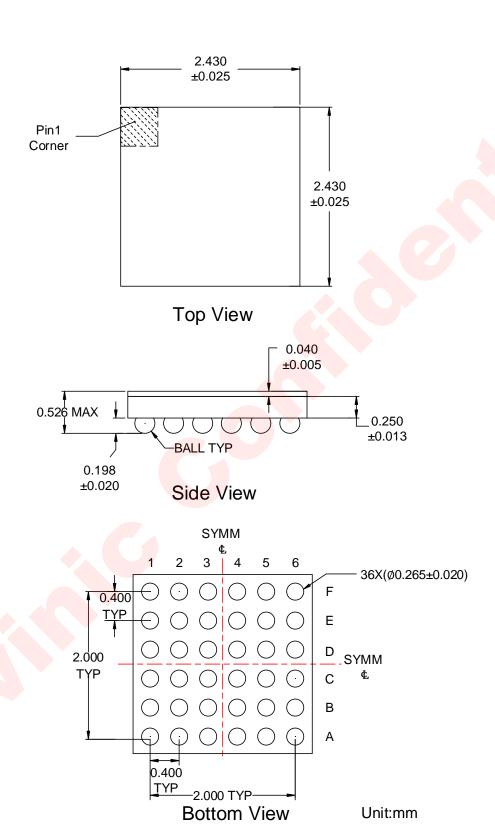
#### DIMENSIONS AND PIN1 ORIENTATION

D1	D0	A0	B0	K0	P0	P1	P2	W	Pin1 Quadrant
(mm)	(mm)	(mm)	(mm)	(mm)	(mm)	(mm)	(mm)	(mm)	Pili Quadrani
179.00	9.00	2.54	2.54	0.76	2.00	4.00	4.00	8.00	Q1

All dimensions are nominal

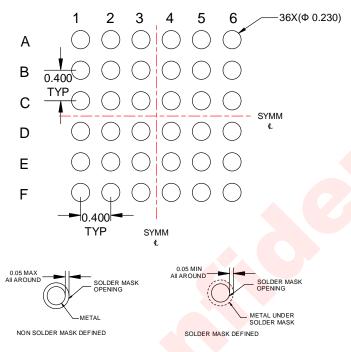
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## **Package Description**



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### **Land Pattern Data**



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# **Revision History**

Version	Date	Change Record	
V1.0	Mar 2019	Datasheet V1.0 released	

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